



# Rare-earth Information Center INSIGHT

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## New Record for NdFeB Energy Product

The latest China Rare Earth Information newsletter (November 1990, No. 19) has a brief announcement concerning a record value for the energy product of a NdFeB permanent magnet. They report that scientists at the Baotou Research Institute of Rare Earth, Baotou, Inner Mongolia used a powder metallurgy technique to prepare a magnet which has an energy product of 52.2 MGOe, a remance of 1.47T and coercivity of 8.36 kOe. Congratulations to the Baotou scientists.

## CeO<sub>2</sub> Buffer Layers for High T<sub>c</sub> Superconductors

One of the major problems for using high temperature superconductors in microwave devices is that the best substrates for epitaxial high T<sub>c</sub> superconducting thin films are not satisfactory, while those which have satisfactory microwave properties (silicon and sapphire) react with the high T<sub>c</sub> materials. One solution to the problem is to use a buffer layer to prevent the chemical reaction between the superconductor and substrate, but will still have an epitaxial film of the superconductor on the substrate. Scientists (X. D. Wu and co-workers) at the Los Alamos National Laboratory have found that CeO<sub>2</sub> thin films on LaAlO<sub>3</sub>, sapphire, and yttria-stabilized zirconia (YSZ) form excellent buffer layers which are chemically and structurally compatible with the YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7-x</sub> (1:2:3) high temperature superconductor. The (100) planes of CeO<sub>2</sub> have a lattice mismatch of 0.16% with the *a* lattice parameter of the 1:2:3 phase and a 1.7% difference with the *b* lattice parameter. The (100) CeO<sub>2</sub> and 1:2:3 films were deposited epitaxially on (100) LaAlO<sub>3</sub>, (100) YSZ, and (1 $\bar{1}$ 02) sapphire (R-cut sapphire) by using a pulsed laser deposition technique. The CeO<sub>2</sub> film thickness varied from 1000 to 2000Å. The 1:2:3 phase was then deposited on the CeO<sub>2</sub> buffer layer. The epitaxial 1:2:3 films had a zero resistance temperature of 90K and a critical current density of 5.9 x 10<sup>6</sup> A/cm<sup>2</sup> at 75K, both of which are state-of-the-art values.

## Superconductor Sandwiches

University of Stanford researchers have been able to grow a multi-layered thin-film sandwich of the YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7</sub> superconductor (Y:1:2:3) in which the optimum current-carrying CuO<sub>2</sub> planes are oriented perpendicular to the surface of the film. Here-to-fore scientists were only able to grow films with the CuO<sub>2</sub> plane oriented parallel to the film surface. But for

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